

10/580,552

01/09/2010

STN: SEARCH

Connecting via Winsock to STN

Welcome to STN International! Enter x:x

LOGINID:sssptal621con

PASSWORD:

TERMINAL (ENTER 1, 2, 3, OR ?):2

* * * * * Welcome to STN International * * * * *

NEWS 1 Web Page for STN Seminar Schedule - N. America
NEWS 2 AUG 10 Time limit for inactive STN sessions doubles to 40
minutes
NEWS 3 AUG 18 COMPENDEX indexing changed for the Corporate Source
(CS) field
NEWS 4 AUG 24 ENCOMPLIT/ENCOMPLIT2 reloaded and enhanced
NEWS 5 AUG 24 CA/CAPLUS enhanced with legal status information for
U.S. patents
NEWS 6 SEP 09 50 Millionth Unique Chemical Substance Recorded in
CAS REGISTRY
NEWS 7 SEP 11 WPIDS, WPINDEX, and WPIX now include Japanese FTERM
thesaurus
NEWS 8 OCT 21 Derwent World Patents Index Coverage of Indian and
Taiwanese Content Expanded
NEWS 9 OCT 21 Derwent World Patents Index enhanced with human
translated claims for Chinese Applications and
Utility Models
NEWS 10 NOV 23 Addition of SCAN format to selected STN databases
NEWS 11 NOV 23 Annual Reload of IFI Databases
NEWS 12 DEC 01 FRFULL Content and Search Enhancements
NEWS 13 DEC 01 DGENE, USGENE, and PCTGEN: new percent identity
feature for sorting BLAST answer sets
NEWS 14 DEC 02 Derwent World Patent Index: Japanese FI-TERM
thesaurus added
NEWS 15 DEC 02 PCTGEN enhanced with patent family and legal status
display data from INPADOCDB
NEWS 16 DEC 02 USGENE: Enhanced coverage of bibliographic and
sequence information
NEWS 17 DEC 21 New Indicator Identifies Multiple Basic Patent
Records Containing Equivalent Chemical Indexing
in CA/CAPLUS

NEWS EXPRESS MAY 26 09 CURRENT WINDOWS VERSION IS V8.4,
AND CURRENT DISCOVER FILE IS DATED 06 APRIL 2009.

NEWS HOURS STN Operating Hours Plus Help Desk Availability
NEWS LOGIN Welcome Banner and News Items

Enter NEWS followed by the item number or name to see news on that
specific topic.

All use of STN is subject to the provisions of the STN customer agreement. This agreement limits use to scientific research. Use for software development or design, implementation of commercial gateways, or use of CAS and STN data in the building of commercial products is prohibited and may result in loss of user privileges and other penalties.

* * * * * STN Columbus * * * * *

FILE 'HOME' ENTERED AT 16:21:21 ON 09 JAN 2010

=> FILE REG

COST IN U.S. DOLLARS

SINCE FILE

TOTAL

ENTRY

SESSION

FULL ESTIMATED COST

0.22

0.22

FILE 'REGISTRY' ENTERED AT 16:21:39 ON 09 JAN 2010

USE IS SUBJECT TO THE TERMS OF YOUR STN CUSTOMER AGREEMENT.

PLEASE SEE "HELP USAGETERMS" FOR DETAILS.

COPYRIGHT (C) 2010 American Chemical Society (ACS)

Property values tagged with IC are from the ZIC/VINITI data file provided by InfoChem.

STRUCTURE FILE UPDATES: 8 JAN 2010 HIGHEST RN 1201769-11-0

DICTIONARY FILE UPDATES: 8 JAN 2010 HIGHEST RN 1201769-11-0

New CAS Information Use Policies, enter HELP USAGETERMS for details.

TSCA INFORMATION NOW CURRENT THROUGH June 26, 2009.

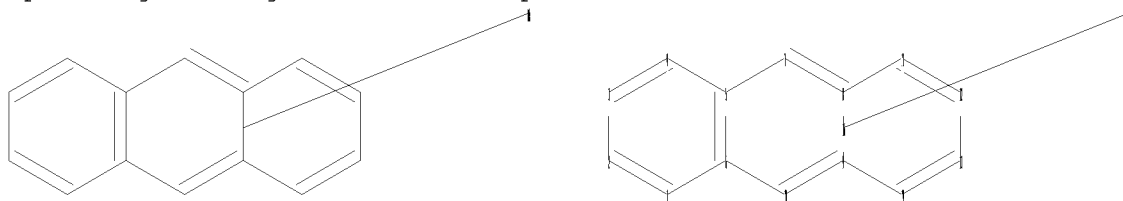
Please note that search-term pricing does apply when conducting SmartSELECT searches.

REGISTRY includes numerically searchable data for experimental and predicted properties as well as tags indicating availability of experimental property data in the original document. For information on property searching in REGISTRY, refer to:

<http://www.cas.org/support/stngen/stndoc/properties.html>

=>

Uploading C:\Program Files\Stnexp\Queries\GOOD4.str



chain nodes :

15

ring nodes :

1 2 3 4 5 6 7 8 9 10 11 12 13 14

ring bonds :

10/580,552

01/09/2010

STN: SEARCH

1-2 1-6 2-3 3-4 4-5 5-6 5-7 6-10 7-8 8-9 8-11 9-10 9-14 11-12 12-13
13-14
normalized bonds :
1-2 1-6 2-3 3-4 4-5 5-6 5-7 6-10 7-8 8-9 8-11 9-10 9-14 11-12 12-13
13-14

Match level :

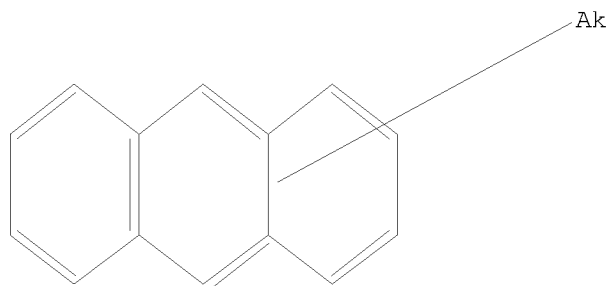
1:Atom 2:Atom 3:Atom 4:Atom 5:Atom 6:Atom 7:Atom 8:Atom 9:Atom 10:Atom
11:Atom 12:Atom 13:Atom 14:Atom 15:CLASS 16:Atom

L1 STRUCTURE UPLOADED

=> D L1

L1 HAS NO ANSWERS

L1 STR



Structure attributes must be viewed using STN Express query preparation.

=> S L1 FULL

FULL SEARCH INITIATED 16:23:00 FILE 'REGISTRY'

FULL SCREEN SEARCH COMPLETED - 562821 TO ITERATE

100.0% PROCESSED 562821 ITERATIONS (3 INCOMPLETE) 38662 ANSWERS
SEARCH TIME: 00.00.14

L2 38662 SEA SSS FUL L1

=> FILE CAPLUS

COST IN U.S. DOLLARS

SINCE FILE

TOTAL

ENTRY

SESSION

FULL ESTIMATED COST

193.01

193.23

FILE 'CAPLUS' ENTERED AT 16:24:03 ON 09 JAN 2010

USE IS SUBJECT TO THE TERMS OF YOUR STN CUSTOMER AGREEMENT.

PLEASE SEE "HELP USAGETERMS" FOR DETAILS.

COPYRIGHT (C) 2010 AMERICAN CHEMICAL SOCIETY (ACS)

Copyright of the articles to which records in this database refer is held by the publishers listed in the PUBLISHER (PB) field (available

for records published or updated in Chemical Abstracts after December 26, 1996), unless otherwise indicated in the original publications. The CA Lexicon is the copyrighted intellectual property of the American Chemical Society and is provided to assist you in searching databases on STN. Any dissemination, distribution, copying, or storing of this information, without the prior written consent of CAS, is strictly prohibited.

FILE COVERS 1907 - 9 Jan 2010 VOL 152 ISS 3
FILE LAST UPDATED: 8 Jan 2010 (20100108/ED)
REVISED CLASS FIELDS (/NCL) LAST RELOADED: Oct 2009
USPTO MANUAL OF CLASSIFICATIONS THESAURUS ISSUE DATE: Oct 2009

CAPLUS now includes complete International Patent Classification (IPC) reclassification data for the third quarter of 2009.

CAS Information Use Policies apply and are available at:

<http://www.cas.org/legal/infopolicy.html>

This file contains CAS Registry Numbers for easy and accurate substance identification.

=> S L2

L3 32086 L2

=> S L3 AND BINDER

211249 BINDER

L4 193 L3 AND BINDER

=> S L4 AND PERMITIVITY

18 PERMITIVITY

L5 0 L4 AND PERMITIVITY

=> S L4 AND SEMICONDUCTING

33118 SEMICONDUCTING

L6 4 L4 AND SEMICONDUCTING

=> D L6 IBIB ABS HITSTR 1-4

L6 ANSWER 1 OF 4 CAPLUS COPYRIGHT 2010 ACS on STN

ACCESSION NUMBER: 2009:1589017 CAPLUS

DOCUMENT NUMBER: 152:57976

TITLE: Process for preparing substituted pentacenes

INVENTOR(S): Tierney, Steven; Heeney, Martin; Bailey, Clare; Zhang, Weimin

PATENT ASSIGNEE(S): Merck Patent GmbH, Germany

SOURCE: PCT Int. Appl., 48pp.

CODEN: PIXXD2

DOCUMENT TYPE: Patent

LANGUAGE: English

FAMILY ACC. NUM. COUNT: 1

PATENT INFORMATION:

PATENT NO.	KIND	DATE	APPLICATION NO.	DATE
-----	----	-----	-----	-----
WO 2008128618	A1	20081030	WO 2008-EP2485	20080328

W: AE, AG, AL, AM, AO, AT, AU, AZ, BA, BB, BG, BH, BR, BW, BY, BZ, CA, CH, CN, CO, CR, CU, CZ, DE, DK, DM, DO, DZ, EC, EE, EG, ES, FI, GB, GD, GE, GH, GM, GT, HN, HR, HU, ID, IL, IN, IS, JP, KE, KG, KM, KN, KP, KR, KZ, LA, LC, LK, LR, LS, LT, LU, LY, MA, MD, ME, MG, MK, MN, MW, MX, MY, MZ, NA, NG, NI, NO, NZ, OM, PG, PH, PL, PT, RO, RS, RU, SC, SD, SE, SG, SK, SL, SM, SV, SY, TJ, TM, TN, TR, TT, TZ, UA, UG, US, UZ, VC, VN, ZA, ZM, ZW

RW: AT, BE, BG, CH, CY, CZ, DE, DK, EE, ES, FI, FR, GB, GR, HR, HU, IE, IS, IT, LT, LU, LV, MC, MT, NL, NO, PL, PT, RO, SE, SI, SK, TR, BF, BJ, CF, CG, CI, CM, GA, GN, GQ, GW, ML, MR, NE, SN, TD, TG, BW, GH, GM, KE, LS, MW, MZ, NA, SD, SL, SZ, TZ, UG, ZM, ZW, AM, AZ, BY, KG, KZ, MD, RU, TJ, TM

EP 2134725 A1 20091223 EP 2008-716713 20080328

R: AT, BE, BG, CH, CY, CZ, DE, DK, EE, ES, FI, FR, GB, GR, HR, HU, IE, IS, IT, LI, LT, LU, LV, MC, MT, NL, NO, PL, PT, RO, SE, SI, SK, TR

PRIORITY APPLN. INFO.:

EP 2007-7947 A 20070419

WO 2008-EP2485 W 20080328

AB The invention relates to a process of preparing substituted pentacenes, to novel pentacenes prepared by this process, to the use of the novel pentacenes as semiconductors or charge transport materials in optical, electrooptical or electronic devices including field effect transistors (FETs), electroluminescent, photovoltaic and sensor devices, and to FETs and other semiconducting components or materials comprising the novel pentacenes. Thus, 1,4,8,11-tetramethyl-6,13-bis(triethylsilyl)ethynyl)pentacene was prepared and used as a semiconductor for an OFET device, showing high mobility and a high on/off ratio.

IT 1173698-76-4P, 1,4,8,11-Tetramethyl-6,13-

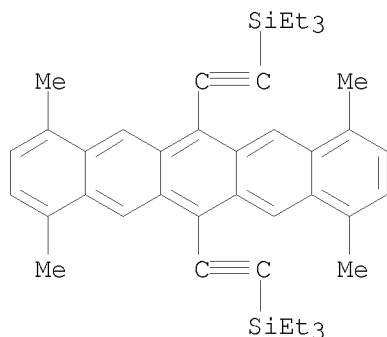
bis(triethylsilyl)ethynyl)pentacene

RL: IMF (Industrial manufacture); TEM (Technical or engineered material use); PREP (Preparation); USES (Uses)

(process for preparing substituted pentacenes as semiconductors or charge transport materials in optical, electrooptical or electronic devices)

RN 1173698-76-4 CAPLUS

CN Pentacene, 1,4,8,11-tetramethyl-6,13-bis[2-(triethylsilyl)ethynyl]- (CA INDEX NAME)



REFERENCE COUNT:

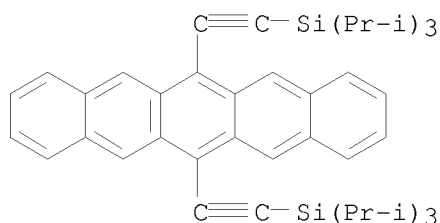
1

THERE ARE 1 CITED REFERENCES AVAILABLE FOR THIS RECORD. ALL CITATIONS AVAILABLE IN THE RE FORMAT

L6 ANSWER 2 OF 4 CAPLUS COPYRIGHT 2010 ACS on STN

ACCESSION NUMBER: 2007:816621 CAPLUS
 DOCUMENT NUMBER: 147:224628
 TITLE: Electronic short channel device comprising an organic semiconductor formulation
 INVENTOR(S): Ogier, Simon Dominic; Veres, Janos; Zeidan, Munther
 PATENT ASSIGNEE(S): Merck Patent G.m.b.H., Germany
 SOURCE: PCT Int. Appl., 46pp.
 CODEN: PIXXD2
 DOCUMENT TYPE: Patent
 LANGUAGE: English
 FAMILY ACC. NUM. COUNT: 1
 PATENT INFORMATION:

PATENT NO.	KIND	DATE	APPLICATION NO.	DATE
WO 2007082584	A1	20070726	WO 2006-EP12300	20061220
W:	AE, AG, AL, AM, AT, AU, AZ, BA, BB, BG, BR, BW, BY, BZ, CA, CH, CN, CO, CR, CU, CZ, DE, DK, DM, DZ, EC, EE, EG, ES, FI, GB, GD, GE, GH, GM, GT, HN, HR, HU, ID, IL, IN, IS, JP, KE, KG, KM, KN, KP, KR, KZ, LA, LC, LK, LR, LS, LT, LU, LV, LY, MA, MD, MG, MK, MN, MW, MX, MY, MZ, NA, NG, NI, NO, NZ, OM, PG, PH, PL, PT, RO, RS, RU, SC, SD, SE, SG, SK, SL, SM, SV, SY, TJ, TM, TN, TR, TT, TZ, UA, UG, US, UZ, VC, VN, ZA, ZM, ZW			
RW:	AT, BE, BG, CH, CY, CZ, DE, DK, EE, ES, FI, FR, GB, GR, HU, IE, IS, IT, LT, LU, LV, MC, NL, PL, PT, RO, SE, SI, SK, TR, BF, BJ, CF, CG, CI, CM, GA, GN, GQ, GW, ML, MR, NE, SN, TD, TG, BW, GH, GM, KE, LS, MW, MZ, NA, SD, SL, SZ, TZ, UG, ZM, ZW, AM, AZ, BY, KG, KZ, MD, RU, TJ, TM			
EP 1974401	A1	20081001	EP 2006-841047	20061220
R:	AT, BE, BG, CH, CY, CZ, DE, DK, EE, ES, FI, FR, GB, GR, HU, IE, IS, IT, LI, LT, LU, LV, MC, NL, PL, PT, RO, SE, SI, SK, TR			
GB 2449023	A	20081105	GB 2008-15037	20061220
DE 112006003179	T5	20090115	DE 2006-112006003179	20061220
JP 2009524226	T	20090625	JP 2008-550646	20061220
CN 101361205	A	20090204	CN 2006-80051140	20080715
KR 2008096781	A	20081103	KR 2008-720354	20080820
PRIORITY APPLN. INFO.:			EP 2006-1282	A 20060121
			WO 2006-EP12300	W 20061220
AB	The invention relates to an improved electronic device, like an organic field emission transistor (OFET), which has a short source to drain channel length and contains an organic semiconducting formulation comprising a semiconducting binder.			
IT	373596-08-8 RL: PRP (Properties); TEM (Technical or engineered material use); USES (Uses) (electronic short channel device comprising an organic semiconductor formulation in organic field emission transistors)			
RN	373596-08-8 CAPLUS			
CN	Pentacene, 6,13-bis[2-[tris(1-methylethyl)silyl]ethynyl]- (CA INDEX NAME)			



OS.CITING REF COUNT: 2 THERE ARE 2 CAPLUS RECORDS THAT CITE THIS RECORD
(2 CITINGS)
REFERENCE COUNT: 6 THERE ARE 6 CITED REFERENCES AVAILABLE FOR THIS
RECORD. ALL CITATIONS AVAILABLE IN THE RE FORMAT

L6 ANSWER 3 OF 4 CAPLUS COPYRIGHT 2010 ACS on STN

ACCESSION NUMBER: 2006:437554 CAPLUS

DOCUMENT NUMBER: 144:479184

TITLE: Process for making an organic field effect transistor
with areas of reduced carrier mobility

INVENTOR(S): Brown, Beverley Anne; Veres, Janos; Ogier, Simon
Dominic

PATENT ASSIGNEE(S): Merck Patent G.m.b.H., Germany

SOURCE: PCT Int. Appl., 24 pp.

CODEN: PIXXD2

DOCUMENT TYPE: Patent

LANGUAGE: English

FAMILY ACC. NUM. COUNT: 1

PATENT INFORMATION:

PATENT NO.	KIND	DATE	APPLICATION NO.	DATE
WO 2006048092	A1	20060511	WO 2005-EP10661	20051004
W:				
AE, AG, AL, AM, AT, AU, AZ, BA, BB, BG, BR, BW, BY, BZ, CA, CH, CN, CO, CR, CU, CZ, DE, DK, DM, DZ, EC, EE, EG, ES, FI, GB, GD, GE, GH, GM, HR, HU, ID, IL, IN, IS, JP, KE, KG, KM, KP, KR, KZ, LC, LK, LR, LS, LT, LU, LV, LY, MA, MD, MG, MK, MN, MW, MX, MZ, NA, NG, NI, NO, NZ, OM, PG, PH, PL, PT, RO, RU, SC, SD, SE, SG, SK, SL, SM, SY, TJ, TM, TN, TR, TT, TZ, UA, UG, US, UZ, VC, VN, YU, ZA, ZM, ZW				
RW:				
AT, BE, BG, CH, CY, CZ, DE, DK, EE, ES, FI, FR, GB, GR, HU, IE, IS, IT, LT, LU, LV, MC, NL, PL, PT, RO, SE, SI, SK, TR, BF, BJ, CF, CG, CI, CM, GA, GN, GQ, GW, ML, MR, NE, SN, TD, TG, BW, GH, GM, KE, LS, MW, MZ, NA, SD, SL, SZ, TZ, UG, ZM, ZW, AM, AZ, BY, KG, KZ, MD, RU, TJ, TM				
EP 1807884	A1	20070718	EP 2005-790320	20051004
EP 1807884	B1	20080702		
R:				
AT, BE, BG, CH, CY, CZ, DE, DK, EE, ES, FI, FR, GB, GR, HU, IE, IS, IT, LI, LT, LU, LV, MC, NL, PL, PT, RO, SE, SI, SK, TR				
JP 2008519445	T	20080605	JP 2007-539481	20051004
AT 400067	T	20080715	AT 2005-790320	20051004
KR 2007083921	A	20070824	KR 2007-710026	20070502
US 20070259477	A1	20071108	US 2007-666751	20070502
PRIORITY APPLN. INFO.:			GB 2004-24342	A 20041103
			WO 2005-EP10661	W 20051004

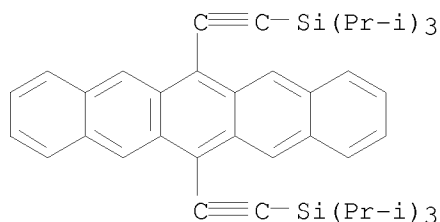
ASSIGNMENT HISTORY FOR US PATENT AVAILABLE IN LSUS DISPLAY FORMAT

AB The present invention relates to a process for reducing the mobility of an organic semiconductor (OSC) layer in an electronic device having a semiconducting channel area. The mobility of the OSC is reduced in specific areas outside the channel area by applying an oxidizing agent to the OSC layer.

IT 373596-08-8
RL: DEV (Device component use); USES (Uses)
(organic semiconductor layer; process for making an organic field effect transistor with areas of reduced carrier mobility)

RN 373596-08-8 CAPLUS

CN Pentacene, 6,13-bis[2-[tris(1-methylethyl)silyl]ethynyl]- (CA INDEX NAME)



REFERENCE COUNT: 4 THERE ARE 4 CITED REFERENCES AVAILABLE FOR THIS RECORD. ALL CITATIONS AVAILABLE IN THE RE FORMAT

L6 ANSWER 4 OF 4 CAPLUS COPYRIGHT 2010 ACS on STN

ACCESSION NUMBER: 2005:523782 CAPLUS

DOCUMENT NUMBER: 143:69829

TITLE: Improvements in and relating to organic semiconducting layers

INVENTOR(S): Brown, Beverley Anne; Veres, Janos; Anemian, Remi Manouk; Williams, Richard Thomas; Ogier, Simon Dominic; Leeming, Stephen William

PATENT ASSIGNEE(S): Avecia Limited, UK

SOURCE: PCT Int. Appl., 68 pp.
CODEN: PIXXD2

DOCUMENT TYPE: Patent

LANGUAGE: English

FAMILY ACC. NUM. COUNT: 1

PATENT INFORMATION:

PATENT NO.	KIND	DATE	APPLICATION NO.	DATE
WO 2005055248	A2	20050616	WO 2004-GB4973	20041125
WO 2005055248	A3	20050728		

W: AE, AG, AL, AM, AT, AU, AZ, BA, BB, BG, BR, BW, BY, BZ, CA, CH, CN, CO, CR, CU, CZ, DE, DK, DM, DZ, EC, EE, EG, ES, FI, GB, GD, GE, GH, GM, HR, HU, ID, IL, IN, IS, JP, KE, KG, KP, KR, KZ, LC, LK, LR, LS, LT, LU, LV, MA, MD, MG, MK, MN, MW, MX, MZ, NA, NI, NO, NZ, OM, PG, PH, PL, PT, RO, RU, SC, SD, SE, SG, SK, SL, SY, TJ, TM, TN, TR, TT, TZ, UA, UG, US, UZ, VC, VN, YU, ZA, ZM, ZW

RW: BW, GH, GM, KE, LS, MW, MZ, NA, SD, SL, SZ, TZ, UG, ZM, ZW, AM, AZ, BY, KG, KZ, MD, RU, TJ, TM, AT, BE, BG, CH, CY, CZ, DE, DK, EE, ES, FI, FR, GB, GR, HU, IE, IS, IT, LU, MC, NL, PL, PT, RO, SE, SI, SK, TR, BF, BJ, CF, CG, CI, CM, GA, GN, GQ, GW, ML, MR, NE, SN, TD, TG

EP 1687830	A2	20060809	EP 2004-819715	20041125
R: AT, BE, CH, DE, DK, ES, FR, GB, GR, IT, LI, LU, NL, SE, MC, PT, IE, SI, FI, RO, CY, TR, BG, CZ, EE, HU, PL, SK, IS				
EP 1783781	A2	20070509	EP 2007-2498	20041125
EP 1783781	A3	20071003		
R: AT, BE, BG, CH, CY, CZ, DE, DK, EE, ES, FI, FR, GB, GR, HU, IE, IS, IT, LI, LU, MC, NL, PL, PT, RO, SE, SI, SK, TR				
JP 2007519227	T	20070712	JP 2006-540612	20041125
EP 1808866	A1	20070718	EP 2007-4534	20041125
R: AT, BE, BG, CH, CY, CZ, DE, DK, EE, ES, FI, FR, GB, GR, HU, IE, IS, IT, LI, LU, MC, NL, PL, PT, RO, SE, SI, SK, TR				
KR 2006110309	A	20061024	KR 2006-710374	20060526
US 20070102696	A1	20070510	US 2006-580552	20060526
US 20070137520	A1	20070621	US 2007-671877	20070206
US 20080009625	A1	20080110	US 2007-822594	20070709
US 7576208	B2	20090818		

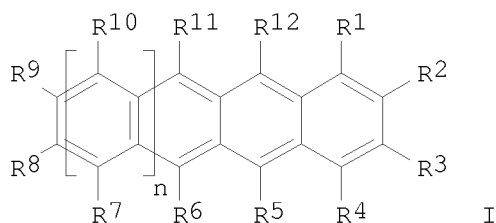
PRIORITY APPLN. INFO.:

GB 2003-27654	A	20031128
GB 2004-7852	A	20040407
GB 2004-14347	A	20040626
EP 2004-819715	A3	20041125
WO 2004-GB4973	W	20041125
US 2006-580552	A3	20060526

ASSIGNMENT HISTORY FOR US PATENT AVAILABLE IN LSUS DISPLAY FORMAT

OTHER SOURCE(S): MARPAT 143:69829

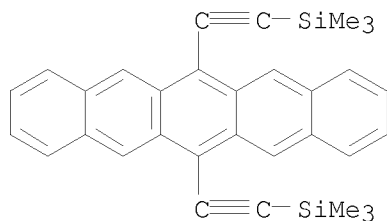
GI



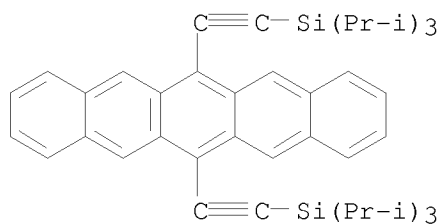
AB An organic semiconducting layer formulation (I), which comprises:
 an organic binder which has a permittivity, ϵ , at 1,000 Hz of 3.3 or less; and a polyacene compound of Formula: A: wherein: each of R1, R2, R3, R4, R5, R6, R7, R8, R9, R10, R11 and R12, which may be the same or different, independently represents hydrogen; an optionally substituted C1-C40 carbyl or hydrocarbyl group; an optionally substituted C1-C40 alkoxy group; an optionally substituted C6-C40 aryloxy group; an optionally substituted C7-C40 alkylaryloxy group; an optionally substituted C2-C40 alkoxy carbonyl group; an optionally substituted C7-C40 aryloxy carbonyl group; a cyano group (-CN); a carbamoyl group (-C(=O)NH₂); a haloformyl group (-C(=O)-X, wherein X represents a halogen atom); a formyl group (-C(=O)-H); an isocyano group; an isocyanate group; a thiocyanate group or a thioisocyanate group; an optionally substituted amino group; a hydroxy group. A nitro group; a CF₃ group; a halo group (Cl, Br, F); or an optionally substituted silyl group; and wherein independently each pair of R2 and R3 and/or R8 and R9, may be cross-bridged to form a C4-C40 saturated or unsatd. ring, which saturated or unsatd. ring may be intervened by an oxygen atom, a sulfur atom or a group shown by formula -N(Ra)- (wherein Ra is a hydrogen atom or an optionally

substituted hydrocarbon group), or may optionally be substituted; and wherein one or more of the carbon atoms of the polyacene skeleton may optionally be substituted by a heteroatom selected from N, P, As, O, S, Se and Te; and wherein independently any two or more of the substituents R1-R12 which are located on adjacent ring positions of the polyacene may, together, optionally constitute a further C4-C40 saturated or unsatd. ring optionally interrupted by O, S or -N(Ra) where Ra is as defined above or an aromatic ring system, fused to the polyacene; and wherein n is 0, 1, 2, 3 or 4, also claimed is an electronic device, particularly.

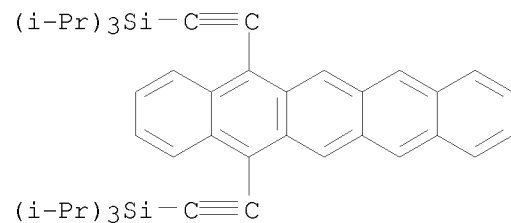
IT 317809-68-0 373596-08-8 373596-09-9
 398128-81-9 775324-33-9 775324-34-0
 854519-90-7 854519-91-8 854519-92-9
 854519-95-2 854519-96-3 854520-00-6
 RL: DEV (Device component use); USES (Uses)
 (improvements in and relating to organic semiconducting layers
 for organic FETs)
 RN 317809-68-0 CAPLUS
 CN Pentacene, 6,13-bis[2-(trimethylsilyl)ethynyl]- (CA INDEX NAME)



RN 373596-08-8 CAPLUS
 CN Pentacene, 6,13-bis[2-[tris(1-methylethyl)silyl]ethynyl]- (CA INDEX NAME)

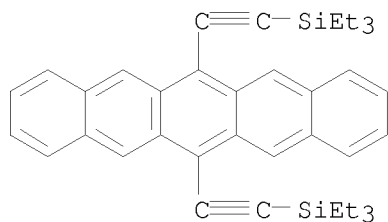


RN 373596-09-9 CAPLUS
 CN Pentacene, 5,14-bis[2-[tris(1-methylethyl)silyl]ethynyl]- (CA INDEX NAME)



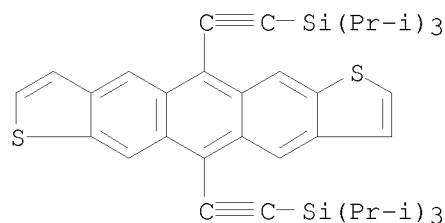
RN 398128-81-9 CAPLUS

CN Pentacene, 6,13-bis[2-(triethylsilyl)ethynyl]- (CA INDEX NAME)



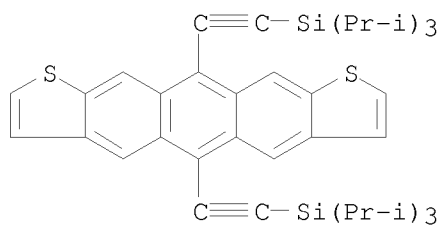
RN 775324-33-9 CAPLUS

CN Anthra[2,3-b:6,7-b']dithiophene, 5,11-bis[2-[tris(1-methylethyl)silyl]ethynyl]- (CA INDEX NAME)



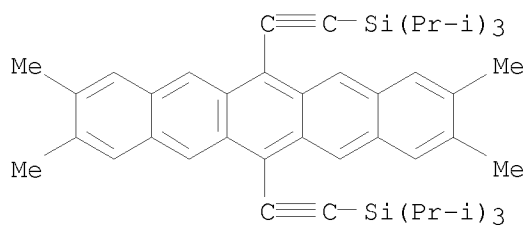
RN 775324-34-0 CAPLUS

CN Silane, (anthra[2,3-b:7,6-b']dithiophene-5,11-diyl-di-2,1-ethynediyl)bis[tris(1-methylethyl)- (9CI) (CA INDEX NAME)



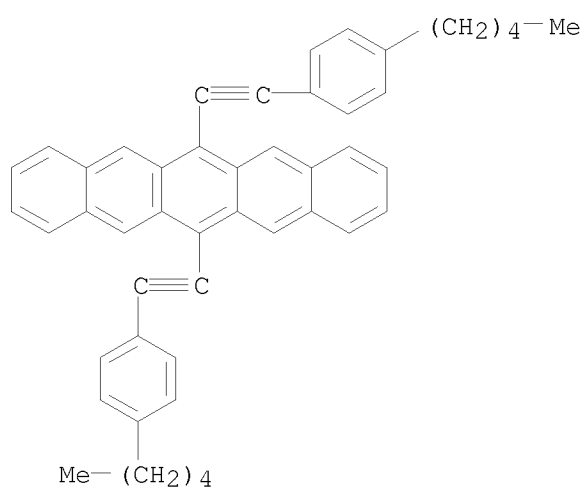
RN 854519-90-7 CAPLUS

CN Pentacene, 2,3,9,10-tetramethyl-6,13-bis[2-[tris(1-methylethyl)silyl]ethynyl]- (CA INDEX NAME)



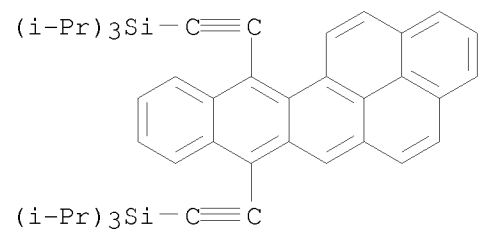
RN 854519-91-8 CAPLUS

CN Pentacene, 6,13-bis[2-(4-pentylphenyl)ethynyl]- (CA INDEX NAME)



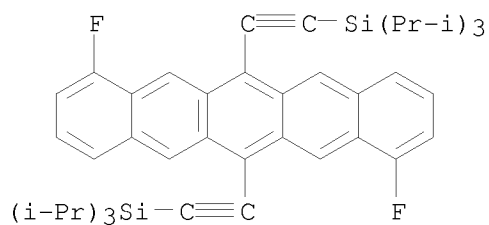
RN 854519-92-9 CAPLUS

CN Dibenzo[1, pqr]benz[a]anthracene, 7,12-bis[2-[tris(1-methylethyl)silyl]ethynyl]- (CA INDEX NAME)

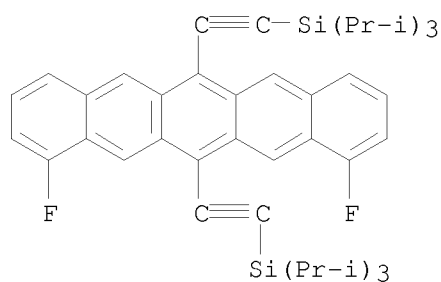


RN 854519-95-2 CAPLUS

CN Pentacene, 1,8-difluoro-6,13-bis[2-[tris(1-methylethyl)silyl]ethynyl]- (CA INDEX NAME)

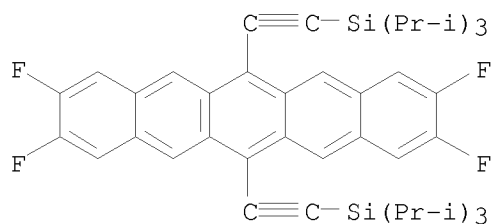


RN 854519-96-3 CAPLUS

CN Pentacene, 1,11-difluoro-6,13-bis[2-[tris(1-methylethyl)silyl]ethynyl]-
(CA INDEX NAME)

RN 854520-00-6 CAPLUS

CN Pentacene, 2,3,9,10-tetrafluoro-6,13-bis[2-[tris(1-methylethyl)silyl]ethynyl]- (CA INDEX NAME)



OS.CITING REF COUNT: 11 THERE ARE 11 CAPLUS RECORDS THAT CITE THIS
RECORD (12 CITINGS)
REFERENCE COUNT: 2 THERE ARE 2 CITED REFERENCES AVAILABLE FOR THIS
RECORD. ALL CITATIONS AVAILABLE IN THE RE FORMAT

=>

---Logging off of STN---

=>

Executing the logoff script...

10/580,552

01/09/2010

STN: SEARCH

=> LOG Y

COST IN U.S. DOLLARS

SINCE FILE

TOTAL

ENTRY

SESSION

FULL ESTIMATED COST

34.17

227.40

DISCOUNT AMOUNTS (FOR QUALIFYING ACCOUNTS)

SINCE FILE

TOTAL

ENTRY

SESSION

CA SUBSCRIBER PRICE

-3.40

-3.40

STN INTERNATIONAL LOGOFF AT 16:28:35 ON 09 JAN 2010